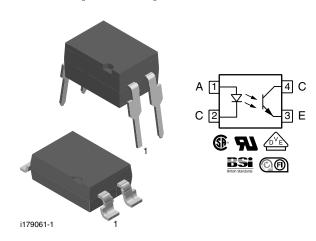


# **Optocoupler, Phototransistor Output, Low Input Current**



### **DESCRIPTION**

The SFH618A (DIP) and SFH6186 (SMD) feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 or SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits. The couplers are end-stackable with 2.54 mm lead spacing. Creepage and clearance distances of > 8 mm achieved with option 6.

#### **FEATURES**

- Good CTR linearity depending on forward current
- · Low CTR degradation
- High collector emitter voltage, V<sub>CEO</sub> = 55 V
- Isolation test voltage, 5300 V<sub>RMS</sub>
- · Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode transient immunity
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

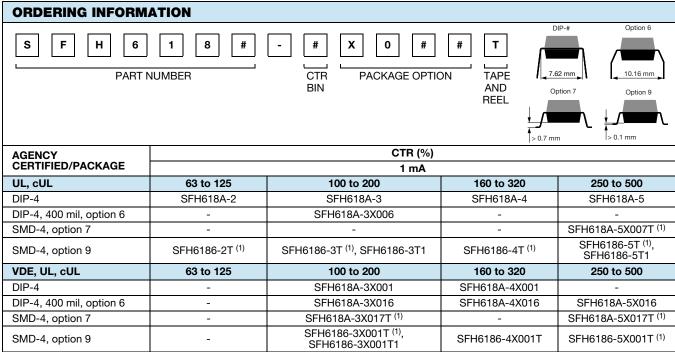
### **APPLICATIONS**

- Telecom
- · Industrial controls
- Battery powered equipment
- · Office machines

### **AGENCY APPROVALS**

The safety application model number covering all products in this datasheet is SFH618A. This model number should be used when consulting safety agency documents.

- UL1577
- cUL
- CSA
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- BSI
- FIMKO



#### Notes

- Additional options may be possible, please contact sales office
- (1) Also available in tubes, do not put T to the end



<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
Reverse voltage		V <sub>R</sub>	6	V				
Power dissipation		P <sub>diss</sub>	70	mW				
Forward current		l <sub>F</sub>	60	mA				
OUTPUT								
Collector emitter voltage		V <sub>CEO</sub>	55	V				
Emitter collector voltage		V <sub>ECO</sub>	7	V				
Collector current		I <sub>C</sub>	50	mA				
	t <sub>p</sub> ≤ 1 ms	I <sub>C</sub>	100	mA				
Power dissipation		P <sub>diss</sub>	150	mW				
COUPLER								
Storage temperature range		T <sub>stg</sub>	-55 to +150	°C				
Ambient temperature range		T <sub>amb</sub>	-55 to +100	°C				
Junction temperature		Tj	125	°C				
Soldering temperature	max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm	T <sub>sld</sub>	260	°C				

### Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability

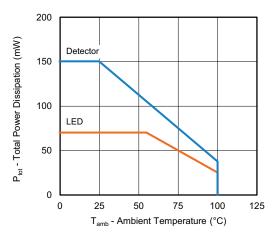


Fig. 1 - Permissible Power Dissipation vs. Ambient Temperature



<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = 5 \text{ mA}$		$V_{F}$	-	1.1	1.5	V
Reverse current	V <sub>R</sub> = 6 V		I <sub>R</sub>	-	0.01	10	μΑ
Capacitance	$V_R = 0 V$ , $f = 1 MHz$		Co	-	25	-	pF
Thermal resistance			R <sub>thja</sub>	-	1070	-	K/W
OUTPUT							
Collector emitter leakage current	V <sub>CE</sub> = 10 V		I <sub>CEO</sub>	-	10	200	nA
Collector emitter capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz		C <sub>CE</sub>	-	7	-	pF
Thermal resistance			R <sub>thja</sub>	-	500	-	K/W
COUPLER							
	I <sub>C</sub> = 0.32 mA, I <sub>F</sub> = 1 mA	SFH618A-2	V <sub>CEsat</sub>	-	0.25	0.4	V
		SFH6186-2	V <sub>CEsat</sub>	-	0.25	0.4	V
	saturation voltage $I_{C}=0.5 \text{ mA, } I_{F}=1 \text{ mA}$ $I_{C}=0.8 \text{ mA, } I_{F}=1 \text{ mA}$ $I_{C}=1.25 \text{ mA, } I_{F}=1 \text{ mA}$	SFH618A-3	V <sub>CEsat</sub>	-	0.25	0.4	V
O-11t		SFH6186-3	V <sub>CEsat</sub>	-	0.25	0.4	V
Collector entitler saturation voltage		SFH618A-4	V <sub>CEsat</sub>	-	0.25	0.4	V
		SFH6186-4	V <sub>CEsat</sub>	-	0.25	0.4	V
		SFH618A-5	V <sub>CEsat</sub>	-	0.25	0.4	V
		SFH6186-5	V <sub>CEsat</sub>	-	0.25	0.4	V
Coupling capacitance			C <sub>C</sub>	-	0.25	-	рF

### Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements

CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
	I <sub>E</sub> = 1 mA, V <sub>CE</sub> = 0.5 V	SFH618A-2	CTR	63	-	125	%
	$I_F = I \text{ IIIA}, V_{CE} = 0.5 \text{ V}$	SFH6186-2	CTR	63	-	125	%
	I <sub>E</sub> = 0.5 mA, V <sub>CE</sub> = 1.5 V	SFH618A-2	CTR	32	75	-	%
	$I_F = 0.5 \text{ IIIA}, V_{CE} = 1.5 \text{ V}$	SFH6186-2	CTR	32	75	-	%
	1 1 m / V 0 F V	SFH618A-3	CTR	100	-	200	%
	$I_F = 1 \text{ mA}, V_{CE} = 0.5 \text{ V}$	SFH6186-3	CTR	100	-	200	%
	1 - 0.5 m/s V/ - 1.5 V/	SFH618A-3	CTR	50	120	-	%
	$I_F = 0.5 \text{ mA}, V_{CE} = 1.5 \text{ V}$	SFH6186-3	CTR	50	120	-	%
I <sub>C</sub> /I <sub>F</sub>	1 1 m / \/ 0 E \/	SFH618A-4	CTR	160	-	320	%
	$I_F = 1 \text{ mA}, V_{CE} = 0.5 \text{ V}$	SFH6186-4	CTR	160	-	320	%
	1 05 mA V 15 V	SFH618A-4	CTR	80	200	-	%
	$I_F = 0.5 \text{ mA}, V_{CE} = 1.5 \text{ V}$	SFH6186-4	CTR	80	200	-	%
	1 1 m / \/ 0 E \/	SFH618A-5	CTR	250	-	500	%
	$I_F = 1 \text{ mA}, V_{CE} = 0.5 \text{ V}$	SFH6186-5	CTR	250	-	500	%
	1 05 mA V 15 V	SFH618A-5	CTR	125	300	-	%
	$I_F = 0.5 \text{ mA}, V_{CE} = 1.5 \text{ V}$	SFH6186-5	CTR	125	300	-	%

<b>SWITCHING CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn on time	$V_{CC}$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$	t <sub>on</sub>	-	6	-	μs
Rise time	$V_{CC}$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$	t <sub>r</sub>	-	3.5	-	μs
Turn off time	$V_{CC}$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$	t <sub>off</sub>	-	5.5	-	μs
Fall time	$V_{CC}$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$	t <sub>f</sub>	-	5	-	μs

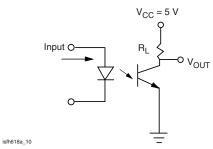


Fig. 2 - Test Circuit

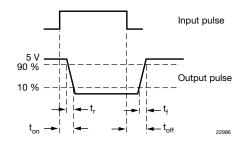


Fig. 3 - Parameter and Limit Definition

SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Climatic classification	According to IEC 68 part 1		55 / 115 / 21			
Pollution degree	According to DIN VDE 0109		2			
Comparative tracking index	Insulation group IIIa	CTI	175			
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V <sub>ISO</sub>	4470	V <sub>RMS</sub>		
Tested withstanding isolation voltage	According to UL1577, t = 1 s	V <sub>ISO</sub>	5300	V <sub>RMS</sub>		
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V <sub>IOTM</sub>	8000	V <sub>peak</sub>		
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V <sub>IORM</sub>	890	V <sub>peak</sub>		
To dollar and state and	$T_{amb} = 25  ^{\circ}\text{C},  V_{IO} = 500  \text{V}$	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω		
Isolation resistance	T <sub>amb</sub> = 100 °C, V <sub>IO</sub> = 500 V	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω		
Output safety power		P <sub>SO</sub>	700	mW		
Input safety current		I <sub>SI</sub>	400	mA		
Input safety temperature		T <sub>S</sub>	175	°C		
Creepage distance	DIP-4		≥ 7	mm		
Clearance distance	DIP-4		≥ 7	mm		
Creepage distance	DID 4 400 mil. antion 6		≥ 8	mm		
Clearance distance	DIP-4, 400 mil, option 6		≥ 8	mm		
Creepage distance	CMD 4 ention 7 and ention 0		≥ 7	mm		
Clearance distance	SMD-4, option 7 and option 9		≥ 7	mm		
Insulation thickness		DTI	≥ 0.4	mm		

#### Note

Rev. 2.8, 29-Mar-18

As per DIN EN 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance
with the safety ratings shall be ensured by means of protective circuits

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

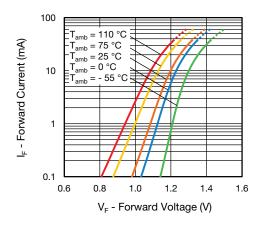


Fig. 4 - Forward Voltage vs. Forward Current

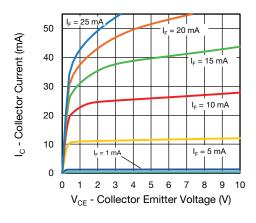


Fig. 5 - Collector Current vs. Collector Emitter Voltage

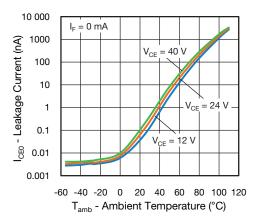


Fig. 6 - Collector Emitter Current vs. Ambient Temperature

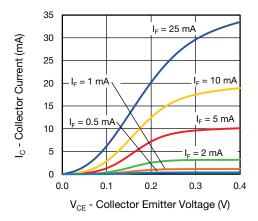


Fig. 7 - Collector Current vs. Collector Emitter Voltage

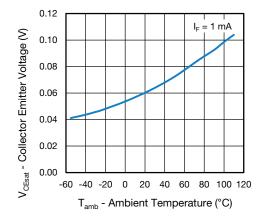


Fig. 8 - Collector Emitter Voltage vs. Ambient Temperature

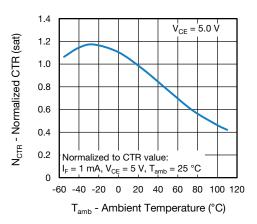


Fig. 9 - Normalized Current Transfer Ratio vs. Ambient Temperature (sat.)

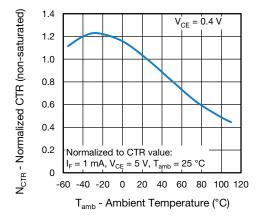


Fig. 10 - Normalized Current Transfer Ratio vs. Ambient Temperature (non-sat.)

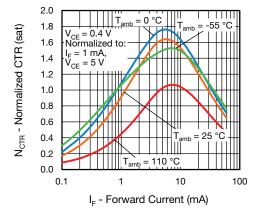


Fig. 11 - Current Transfer Ratio vs. Forward Current (sat.)

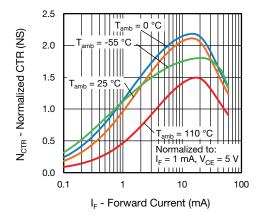


Fig. 12 - Current Transfer Ratio vs. Forward Current (non-sat.)

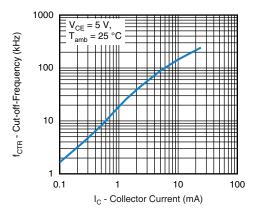


Fig. 13 - Cut-Off Frequency vs. Collector Current

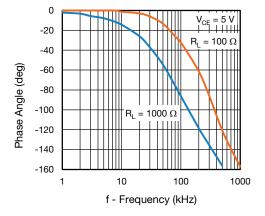


Fig. 14 - Phase Angle vs. Frequency

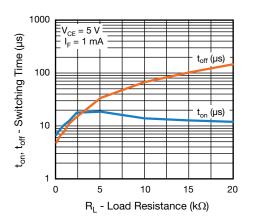


Fig. 15 - Switching Time vs. Load Resistance

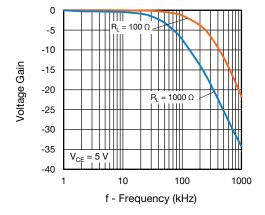
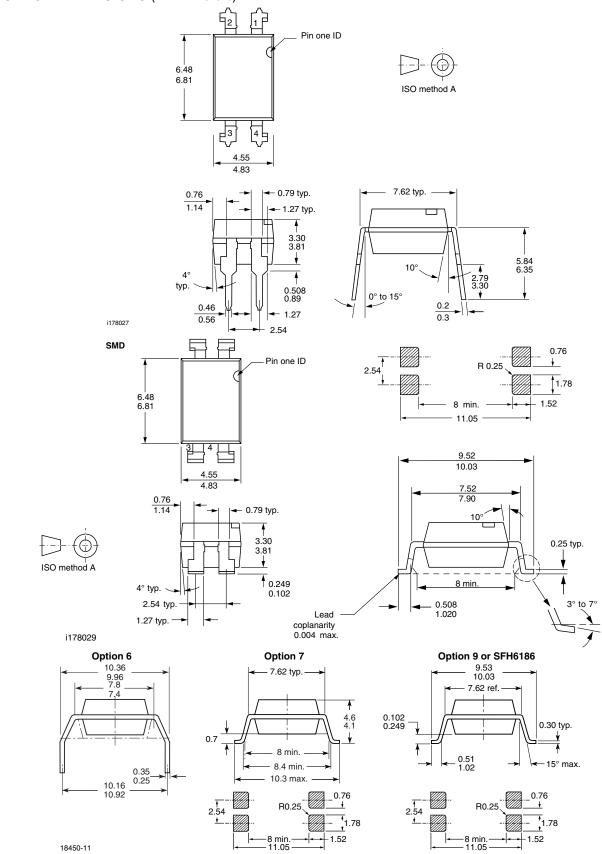


Fig. 16 - Voltage Gain vs. Frequency



### **PACKAGE DIMENSIONS** (in millimeters)





### PACKAGE MARKING (example of SFH618A-3X001)



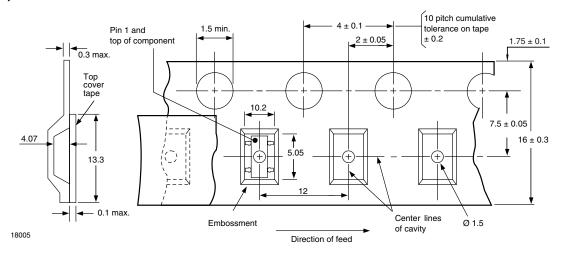
### Notes

- VDE logo is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking

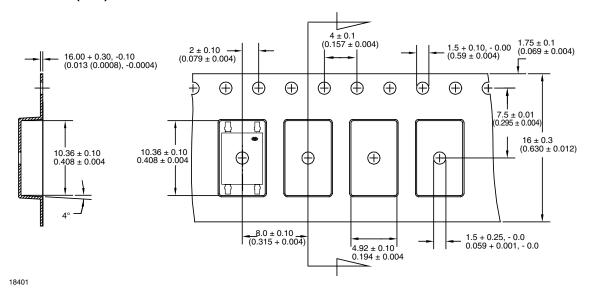
### TAPE AND REEL PACKAGING (in millimeters)

The tape is 16 mm and is wound on a 33 cm reel. There are 1000 parts per reel. Taped and reeled 4 pin optocouplers conform to EIA-481-2 and IEC60286-3.

### SMD-4 ("T")



### SMD-4, 90° Rotation ("T1")



### **SOLDER PROFILES**

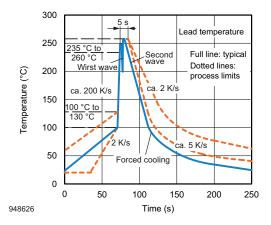


Fig. 17 - Recommended Wave Soldering Double Wave Profile for DIP Devices

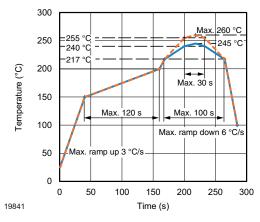


Fig. 18 - Recommended Lead (Pb)-free Reflow Solder Profile for SMD Devices

### HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions:  $T_{amb}$  < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



## **Legal Disclaimer Notice**

Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.